NSN 5962-01-351-5736

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View Online at https://aerobasegroup.com/nsn/5962-01-351-5736

Overall Length:

Between 1.050 inches and 1.260 inches

Overall Height:

Between 0.325 inches and 0.400 inches

Body Length:

Between 1.050 inches and 1.260 inches

Body Width:

Between 0.260 inches and 0.310 inches

Body Height:

Between 0.040 inches and 0.185 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Satellite communications terminal an/usc-3 (v) 1

Features Provided:

Static operation and w/enable and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

19 input

Criticality Code Justification:

Feat

Current Rating Per Characteristic:

50.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Memory Device Type:

Ram

Special Features:

Nuclear hardness critical item

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type A	and Quantity	/ :
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22 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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